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Fitting Havriliak-Negami Equation

Outline

- Description (what is studied and how)
- Study using OriginLab (finding the best fit for the Havriliak-Negami equation with conductivity term)
- Validation using different tool (Scipy, restricting the parameters, initial guess, correlation matrix)
- Suggestions for improvement (Decreasing input errors mainly via improved Area measurements)

Context

- Study of dielectric properties of a thin film of Lithium Niobate at 100°C, used as dielectric in a capacitor subjected to AC electric field at different frequencies (impedance spectroscopy).
- Determination of complex permittivity ($\epsilon = \epsilon' - i\epsilon''$) through the following relations involving measured quantities:
 - Capacitance: $C = \epsilon' \epsilon_0 \frac{A}{d}$
 - Tangent loss: $\tan(\delta) = \frac{\epsilon''}{\epsilon'}$

Debye Model

- Dipolar polarization is the main type of polarization in the range of frequencies considered.
- D.M. describes dielectric relaxation response of dipoles to alternating electrical field $E = E_0 e^{i\omega t}$ considering a single relaxation time τ .

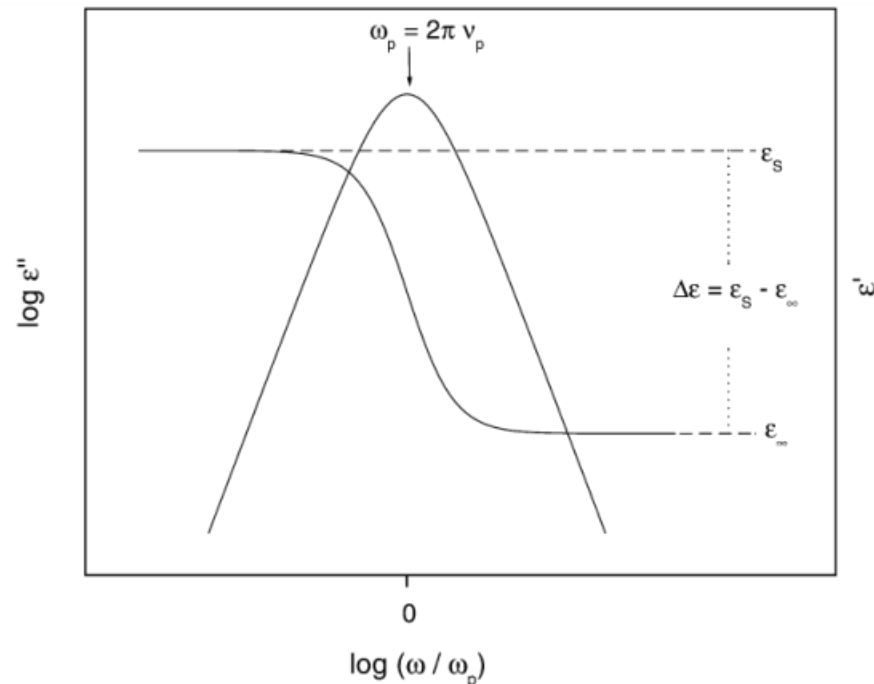
$$\frac{dP_d}{dt} = \frac{1}{\tau} [(\epsilon_s - \epsilon_\infty)E - P_d(t)] \longrightarrow P_d(t) = \frac{\epsilon_s - \epsilon_\infty}{1 + i\omega\tau} E = \frac{\Delta\epsilon}{1 + i\omega\tau} E$$

$$\epsilon = \epsilon_\infty + \frac{\Delta\epsilon}{1 + i\omega\tau}$$

ϵ_s – stationary permittivity, low freqs.
 ϵ_∞ – limit of permittivity for high freqs.

Havriliak–Negami Model

Empirical modification of Debye model to account for the broadening (β) and asymmetry (γ) of dielectric dispersion curve, considering that there is a distribution of relaxation times instead of one time only.



Debye:

$$\epsilon = \epsilon_\infty + \frac{\Delta\epsilon}{1 + i\omega\tau}$$

Havriliak-Negami

$$\epsilon = \epsilon_\infty + \frac{\Delta\epsilon}{(1 + (i\omega\tau)^\beta)^\gamma}$$

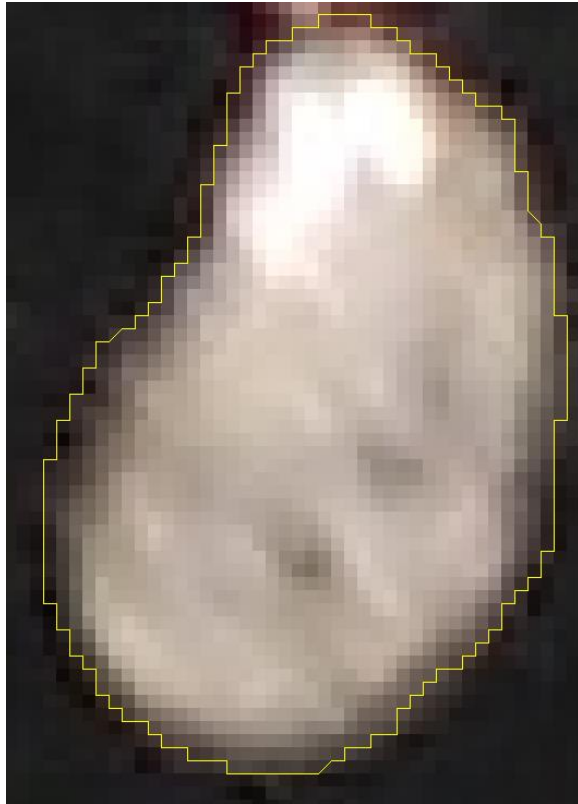
Fig. 3.2. Real ϵ' and imaginary part ϵ'' of the complex dielectric function vs normalized frequency for a Debye relaxation process

Conductive term

- Contributing to the dielectric function there are conductive processes alongside relaxation, which are important in low frequencies.
- Of pure electronic origin, we have a contribution for the imaginary part of ϵ , $\frac{\sigma_{DC}}{\epsilon_0 \omega}$.
- To account for other contributions we add an exponent $s \leq 1$ in ω :

$$\frac{\sigma_{DC}}{\epsilon_0 \omega^s}$$

Area Calculation



Problems:

- Limits
- Shadows
- Superficial curvature

$$\textit{Area} = 1,521 \pm 0,165 \mu\textit{m}$$

Data Error

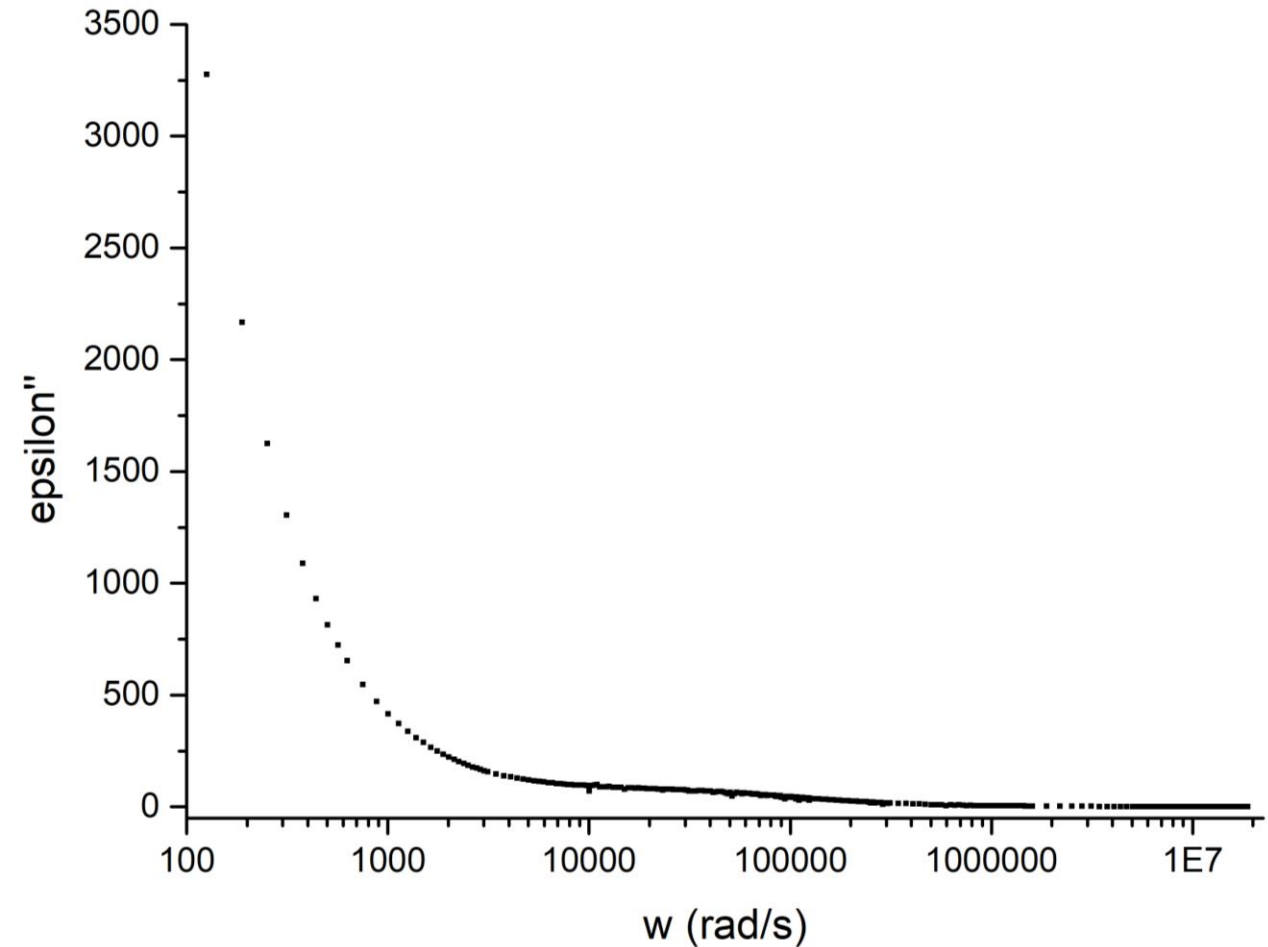
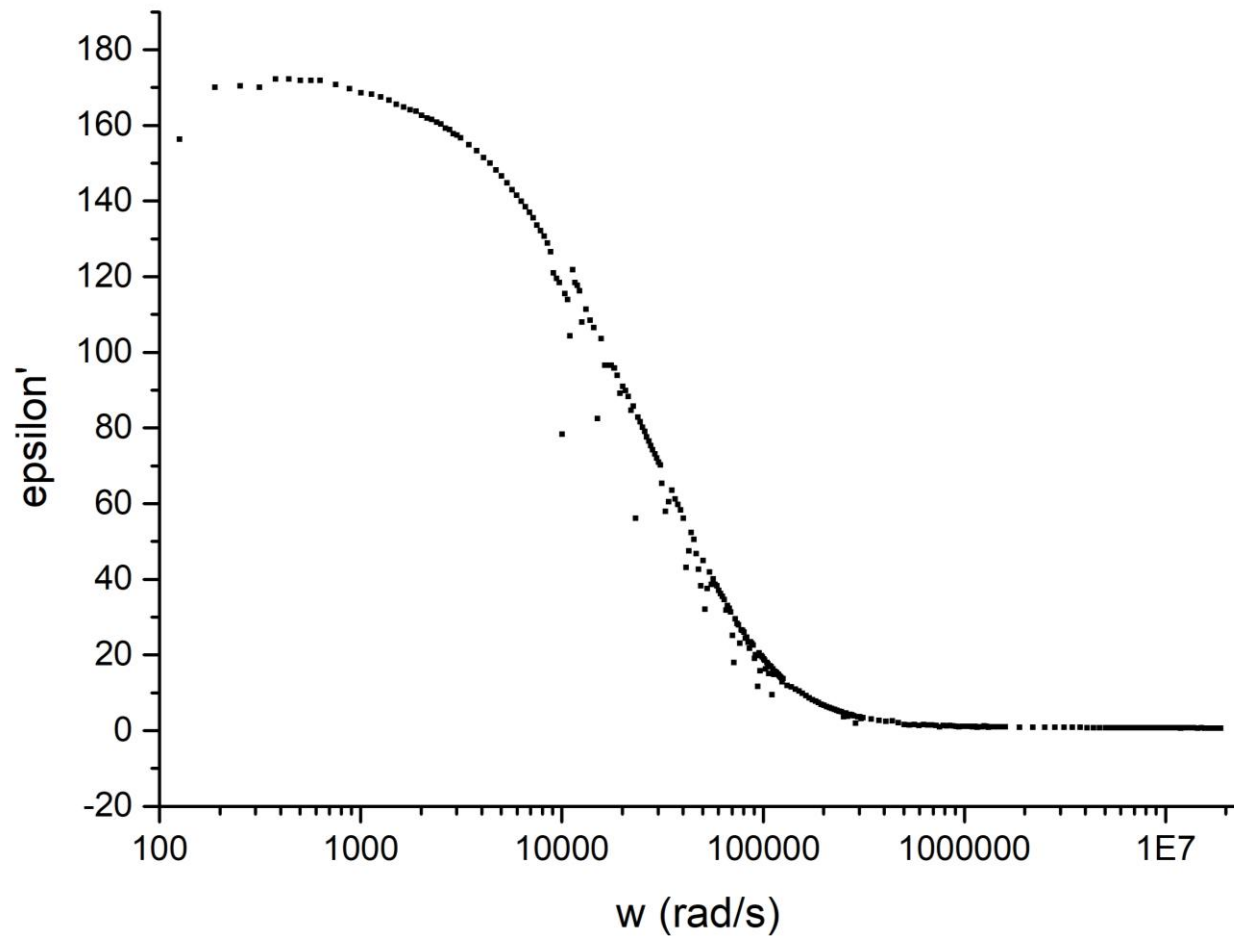
$$\delta f(x_1, x_2, \dots) = \sqrt{\left(\frac{\partial f}{\partial x_1}\right)^2 \delta x_1^2 + \left(\frac{\partial f}{\partial x_2}\right)^2 \delta x_2^2 + \dots}$$

Lab Measurements error: 1%

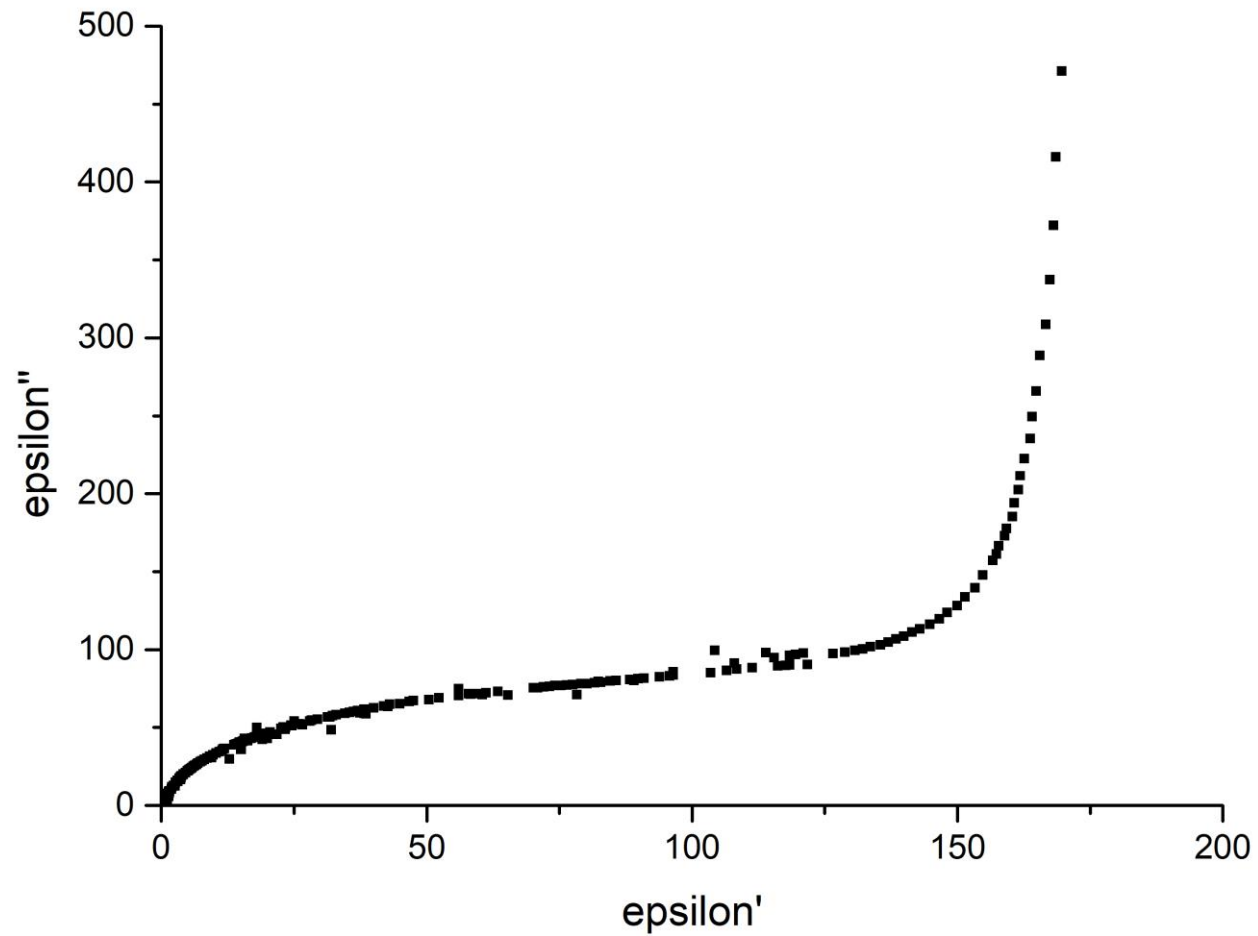
Area error: 10,9%

Real and Imaginary Permittivity error: 10,9%

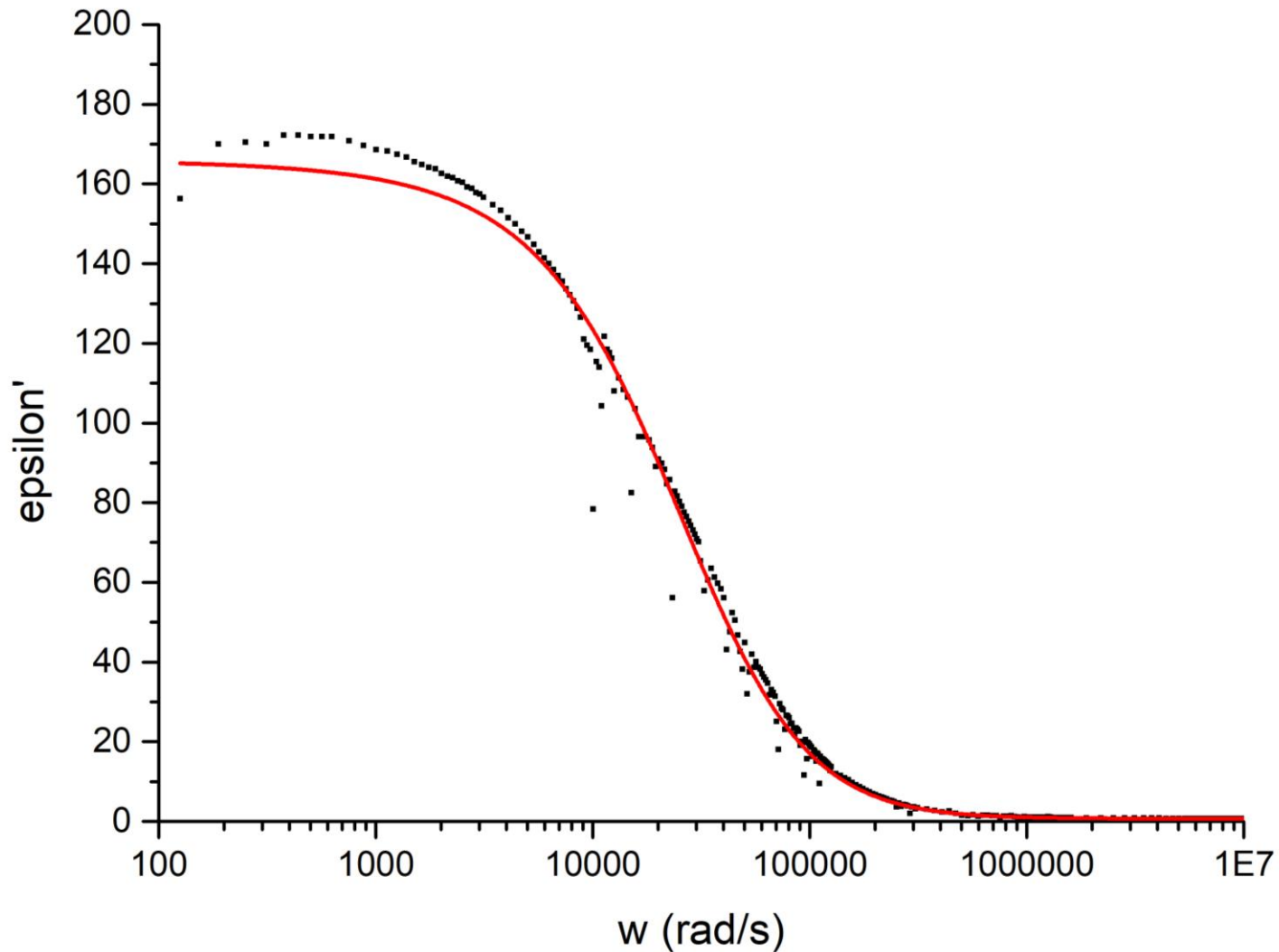
Data: Real and Imaginary Permittivity vs Angular Frequency



Data: Cole-Cole Diagram



Fitting Havriliak-Negami Equation: Real Part



$$\varepsilon' = \varepsilon_{\infty} + \Delta\varepsilon * r(\omega) * \cos(\gamma\varphi(\omega))$$

$$r(\omega) = \left[1 + 2(\omega\tau_{HN})^{\beta} \cos\left(\frac{\beta\pi}{2}\right) + (\omega\tau_{HN})^{2\beta} \right]^{-\gamma/2}$$

$$\varphi(\omega) = \arctan\left[\frac{\sin(\beta\pi/2)}{(\omega\tau_{HN})^{-\beta} + \cos(\beta\pi/2)}\right]$$

Parameters:

$$\Delta\varepsilon = 165 \pm 4$$

$$\beta = 0,80 \pm 0,02$$

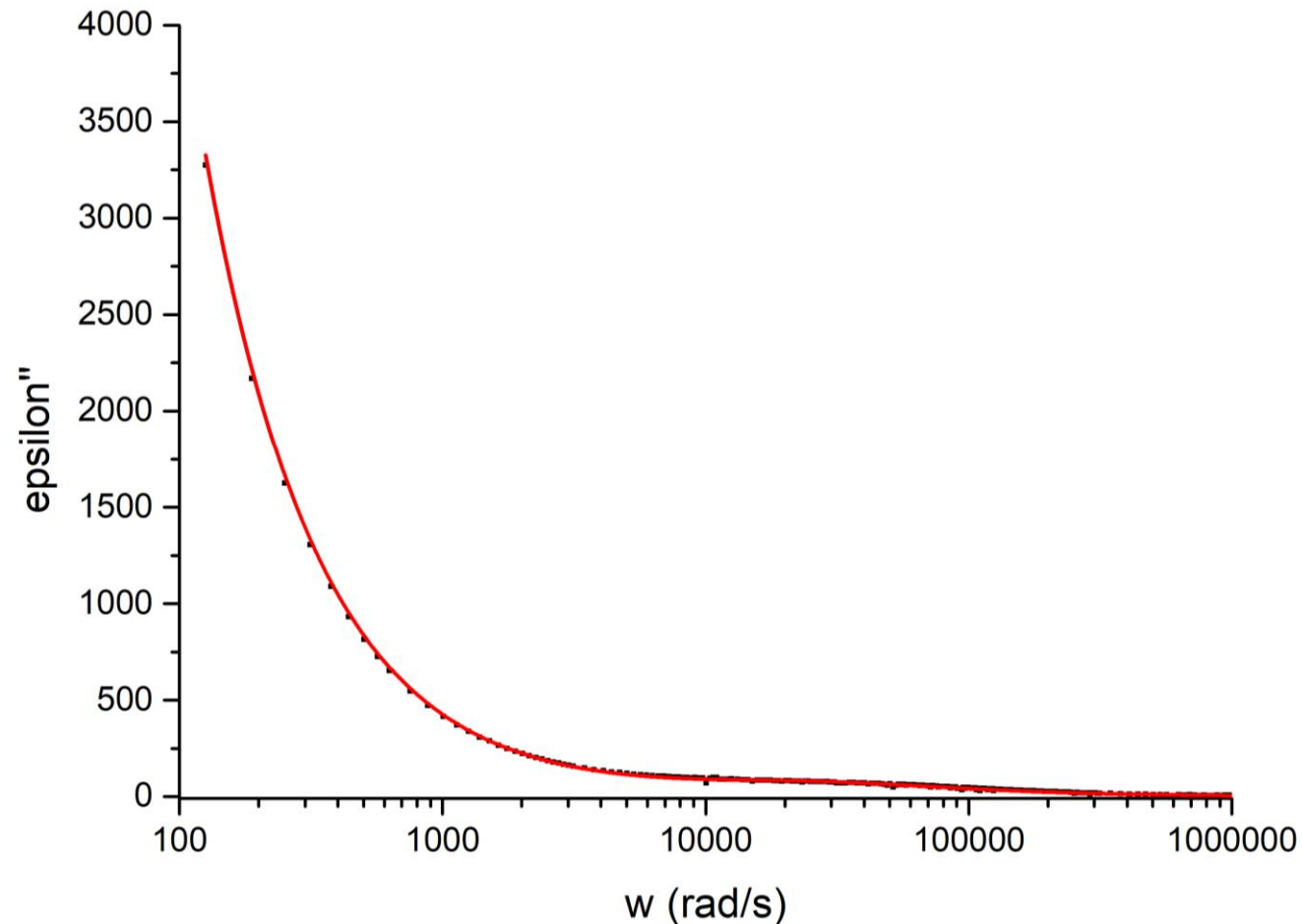
$$\gamma = 1,25 \pm 0,03$$

$$\tau = 3,17 \pm 0,07 (10^{-5}) \text{ s}$$

$$\varepsilon_{\infty} = 0,73 \pm 0,02$$

$$\chi_{red}^2 = 138,59$$

Fitting Havriliak-Negami Equation with Conductivity term: Imaginary Part



$$\varepsilon'' = \Delta\varepsilon * r(\omega) * \sin(\gamma\varphi(\omega)) + \frac{\sigma'}{\omega^s}$$

$$r(\omega) = \left[1 + 2(\omega\tau_{HN})^\beta \cos\left(\frac{\beta\pi}{2}\right) + (\omega\tau_{HN})^{2\beta} \right]^{-\gamma/2}$$

$$\varphi(\omega) = \arctan \left[\frac{\sin(\beta\pi/2)}{(\omega\tau_{HN})^{-\beta} + \cos(\beta\pi/2)} \right]$$

Parameters ($s = 1$):

$$\Delta\varepsilon = 152 \pm 4$$

$$\beta = 0,86 \pm 0,02$$

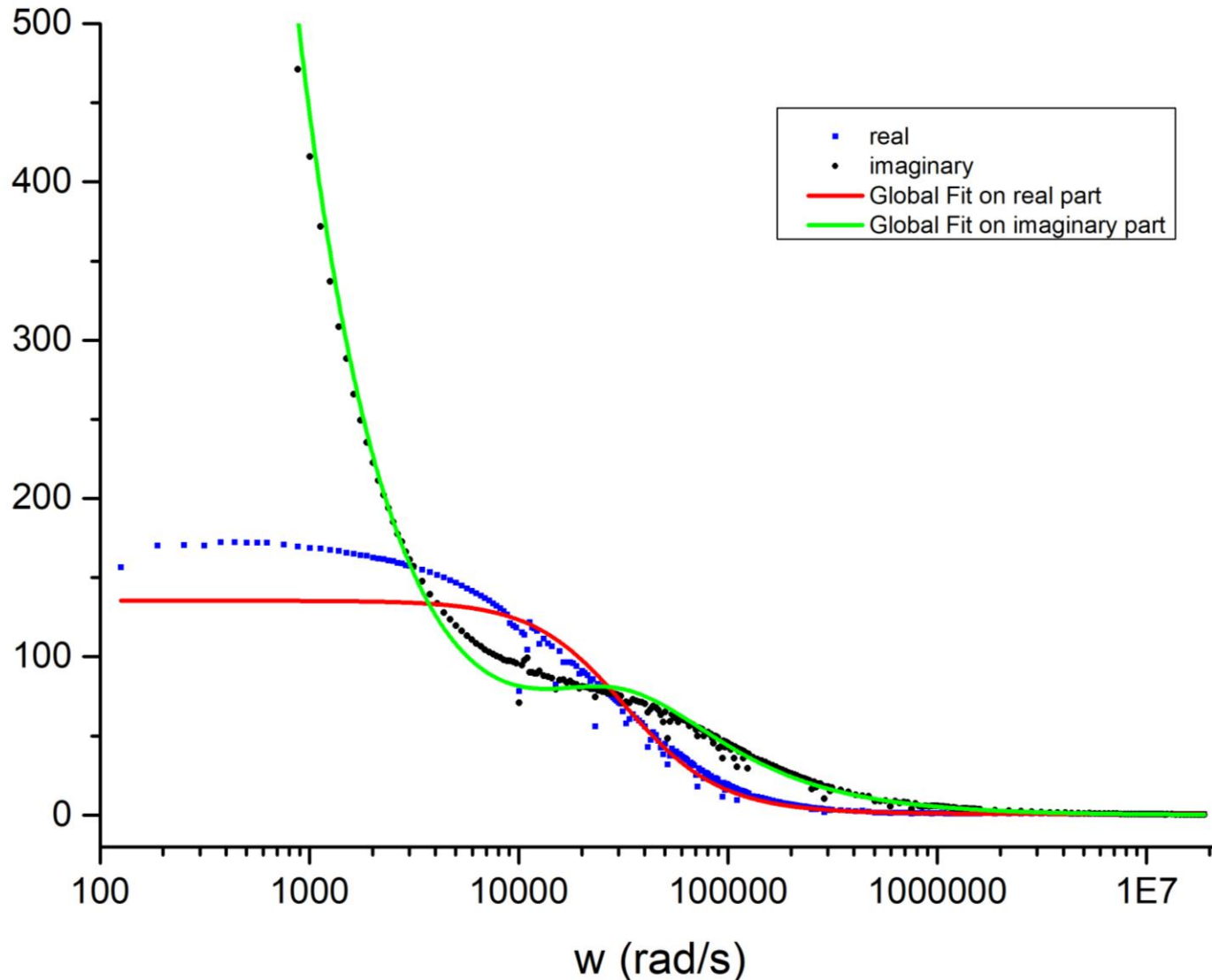
$$\gamma = 1,11 \pm 0,04$$

$$\tau = 3,46 \pm 0,11 (10^{-5}) \text{ s}$$

$$\sigma' = 4,18 \pm 0,09 (10^5) [\Omega^{-1}m^{-1}\varepsilon_0]$$

$$\chi_{red}^2 = 95,93$$

Global Fit: fixed s on conductivity term



$$\varepsilon' = \varepsilon_{\infty} + \Delta\varepsilon * r(\omega) * \cos(\gamma\varphi(\omega))$$

$$\varepsilon'' = \Delta\varepsilon * r(\omega) * \sin(\gamma\varphi(\omega)) + \frac{\sigma}{\omega^s}$$

$$r(\omega) = \left[1 + 2(\omega\tau_{HN})^{\beta} \cos\left(\frac{\beta\pi}{2}\right) + (\omega\tau_{HN})^{2\beta} \right]^{-\gamma/2}$$

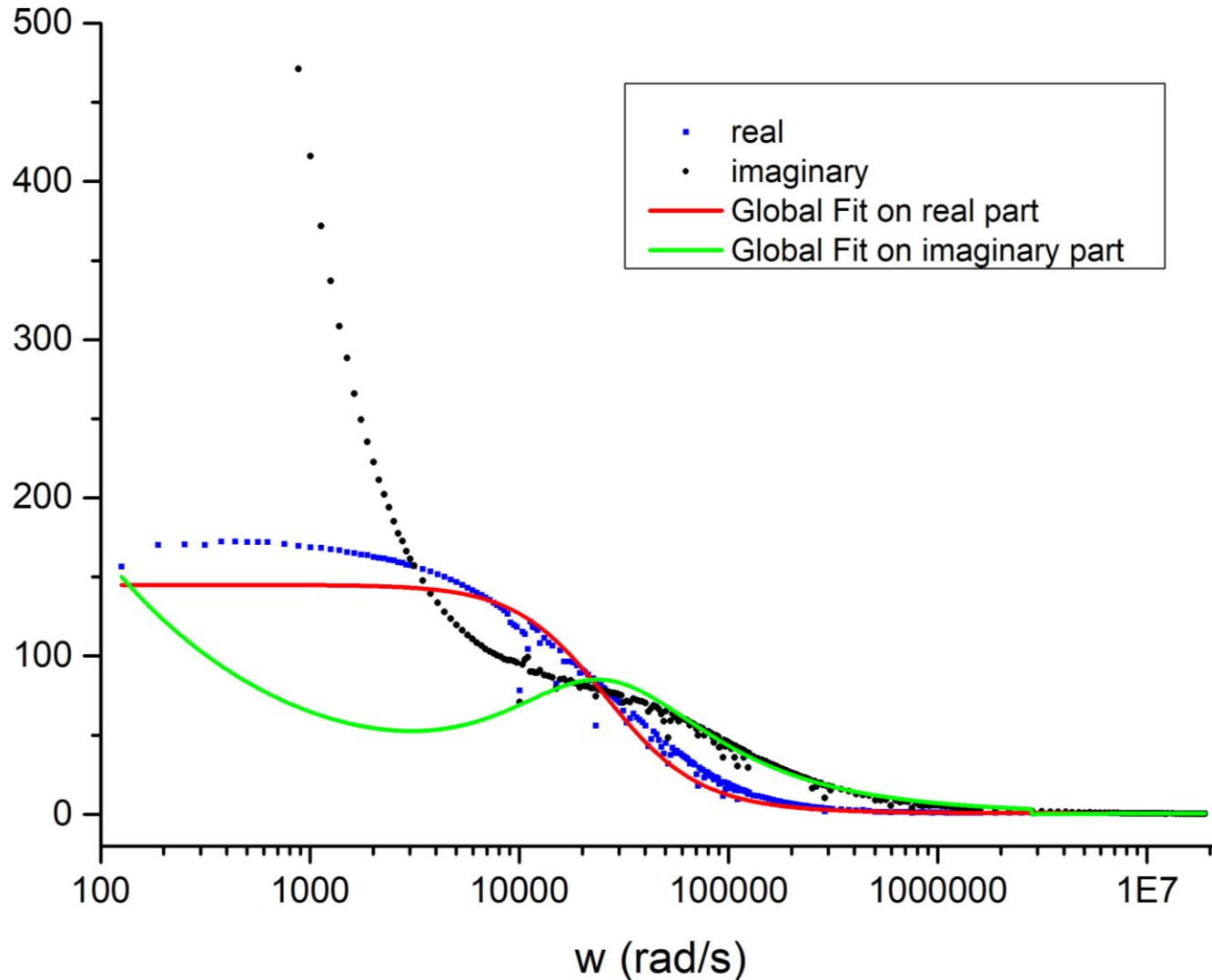
$$\varphi(\omega) = \arctan\left[\frac{\sin(\beta\pi/2)}{(\omega\tau_{HN})^{-\beta} + \cos(\beta\pi/2)}\right]$$

Parameters ($s = 1$):

$$\begin{aligned} \Delta\varepsilon &= 134 \pm 2 \\ \beta &= 0,996 \pm 0,001 \\ \gamma &= 0,955 \pm 0,003 \\ \tau &= 3,21 \pm 0,06 (10^{-5}) s \\ \varepsilon_{\infty} &= 0,65 \pm 0,02 \\ \sigma' &= 4,40 \pm 0,09 (10^5) [\Omega^{-1} m^{-1} \varepsilon_0] \end{aligned}$$

$$\chi_{red}^2 = 162,42$$

Global Fit: varying s on conductivity term

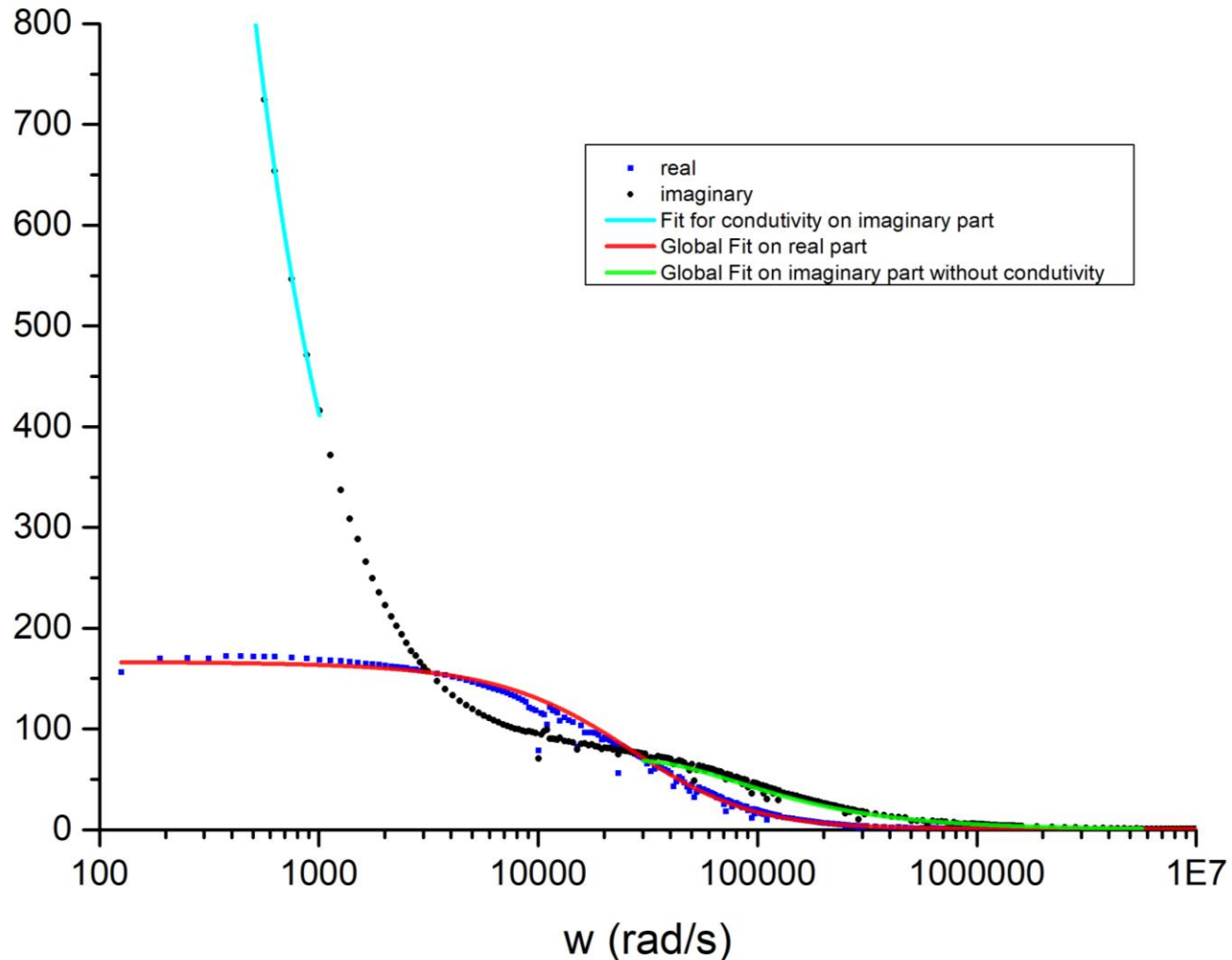


Parameters:

$$\begin{aligned}\Delta\varepsilon &= 144 \pm 4 \\ \beta &= 1,01 \pm 0,01 \\ \gamma &= 0,940 \pm 0,006 \\ \tau &= 4,05 \pm 0,01 (10^{-5}) s \\ \varepsilon_\infty &= 0,67 \pm 0,04 \\ \sigma' &= 1,28 \pm 0,42 (10^3) [\Omega^{-1}m^{-1}\varepsilon_0] \\ s &= 0,44 \pm 0,02\end{aligned}$$

$$\chi_{red}^2 = 938,87$$

Global Fit: Separating H-N equation to Conductivity term on imaginary part



Parameters:

$$\Delta\varepsilon = 166 \pm 4$$

$$\beta = 0,84 \pm 0,02$$

$$\gamma = 1,18 \pm 0,03$$

$$\tau = 3,21 \pm 0,07 (10^{-5})s$$

$$\varepsilon_{\infty} = 0,71 \pm 0,02$$

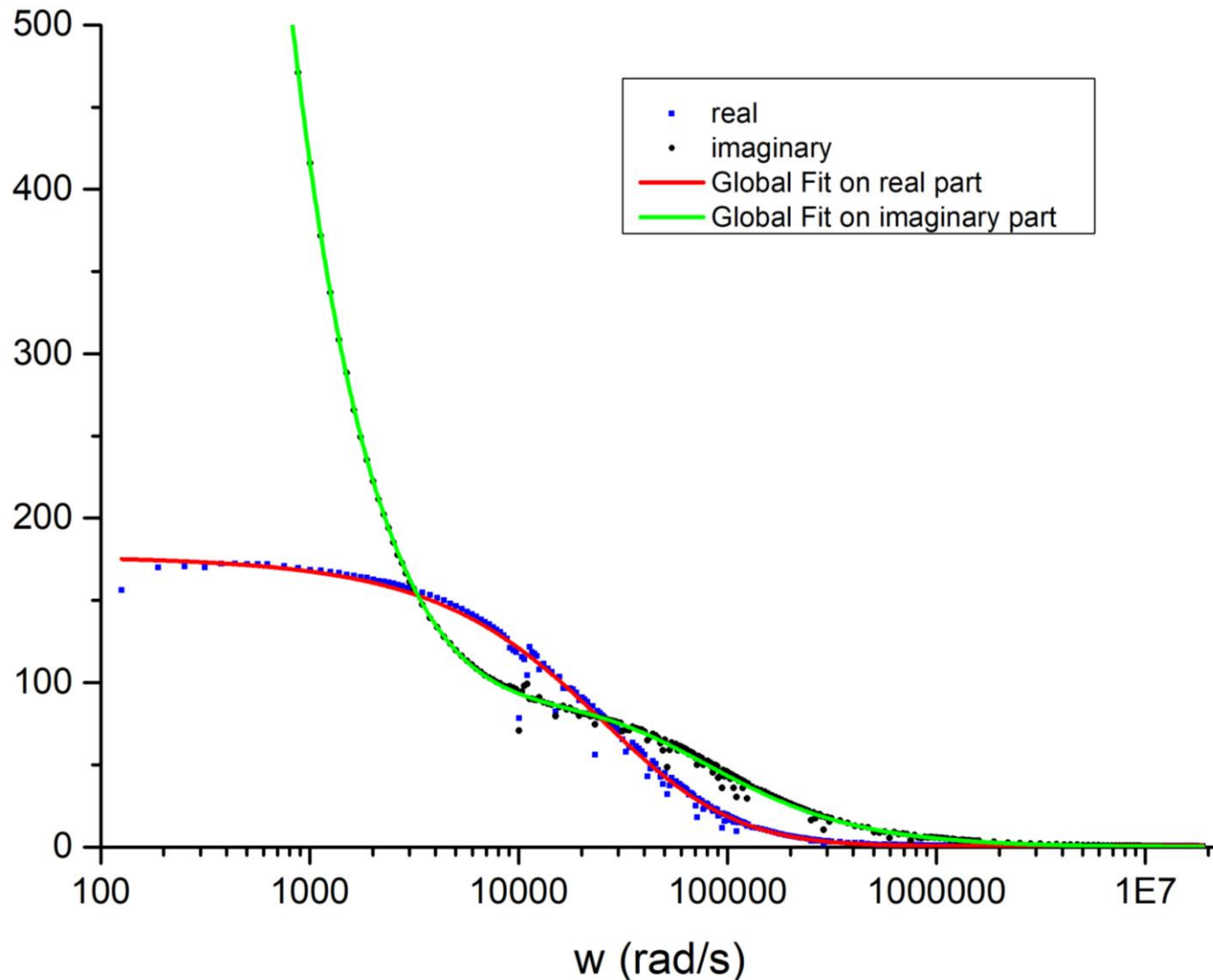
$$\chi_{red}^2 = 152,06$$

$$\sigma' = 3,96 \pm 0,07 (10^5) [\Omega^{-1}m^{-1}\varepsilon_0]$$

$$s = 0,994 \pm 0,003$$

$$\chi_{red}^2 = 0,32$$

Global fit: with initial guess

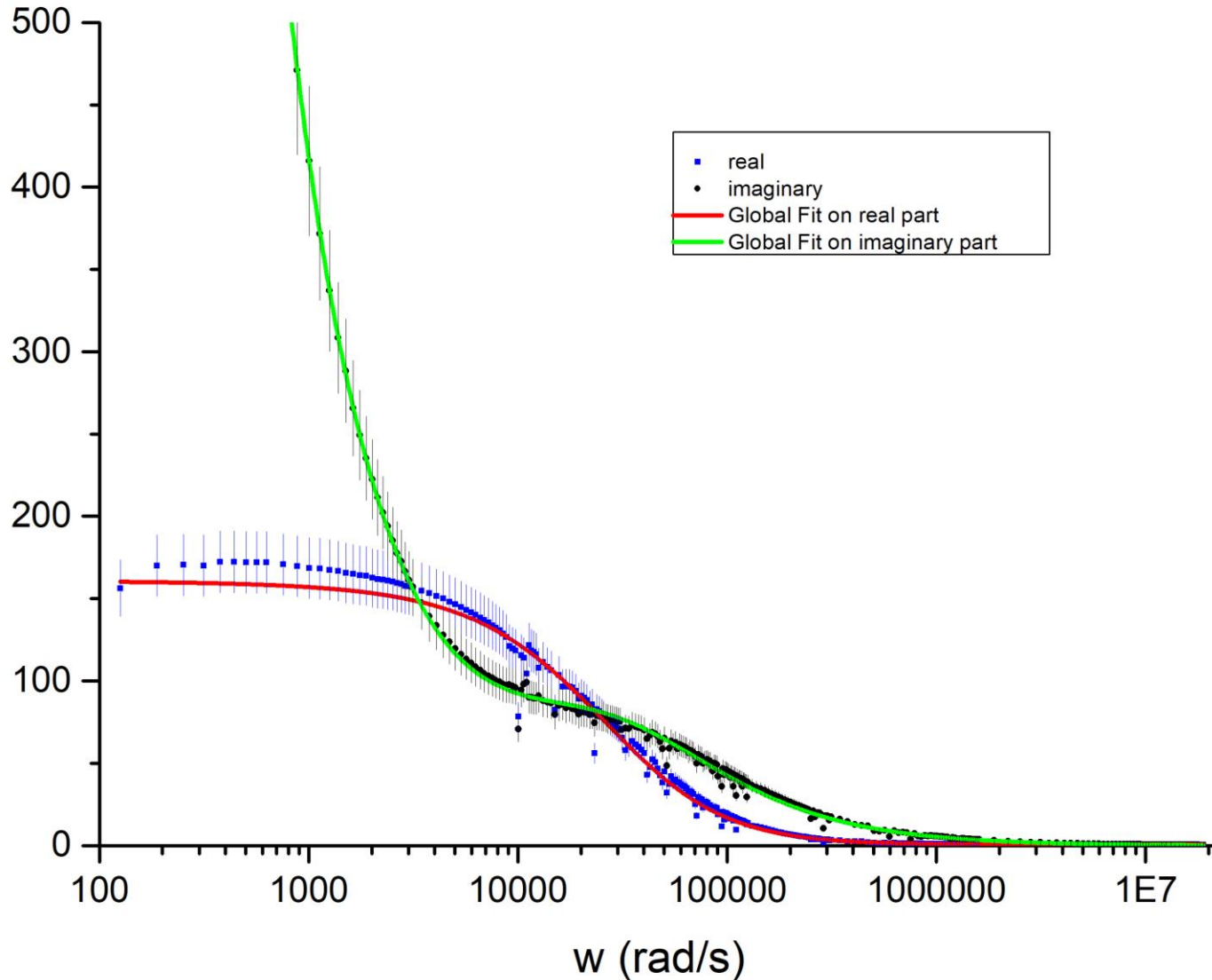


Parameters:

$$\begin{aligned}\Delta\varepsilon &= 176 \pm 1 \\ \beta &= 0,70 \pm 0,010 \\ \gamma &= 1,56 \pm 0,07 \\ \tau &= 2,37 \pm 0,17 (10^{-5})s \\ \varepsilon_{\infty} &= 0,93 \pm 0,39 \\ \sigma' &= 4,34 \pm 0,03 (10^5) [\Omega^{-1}m^{-1}\varepsilon_0] \\ s &= 1,0 \pm 0,01\end{aligned}$$

$$\chi_{red}^2 = 11,68$$

Global Fit: with errors



Parameters:

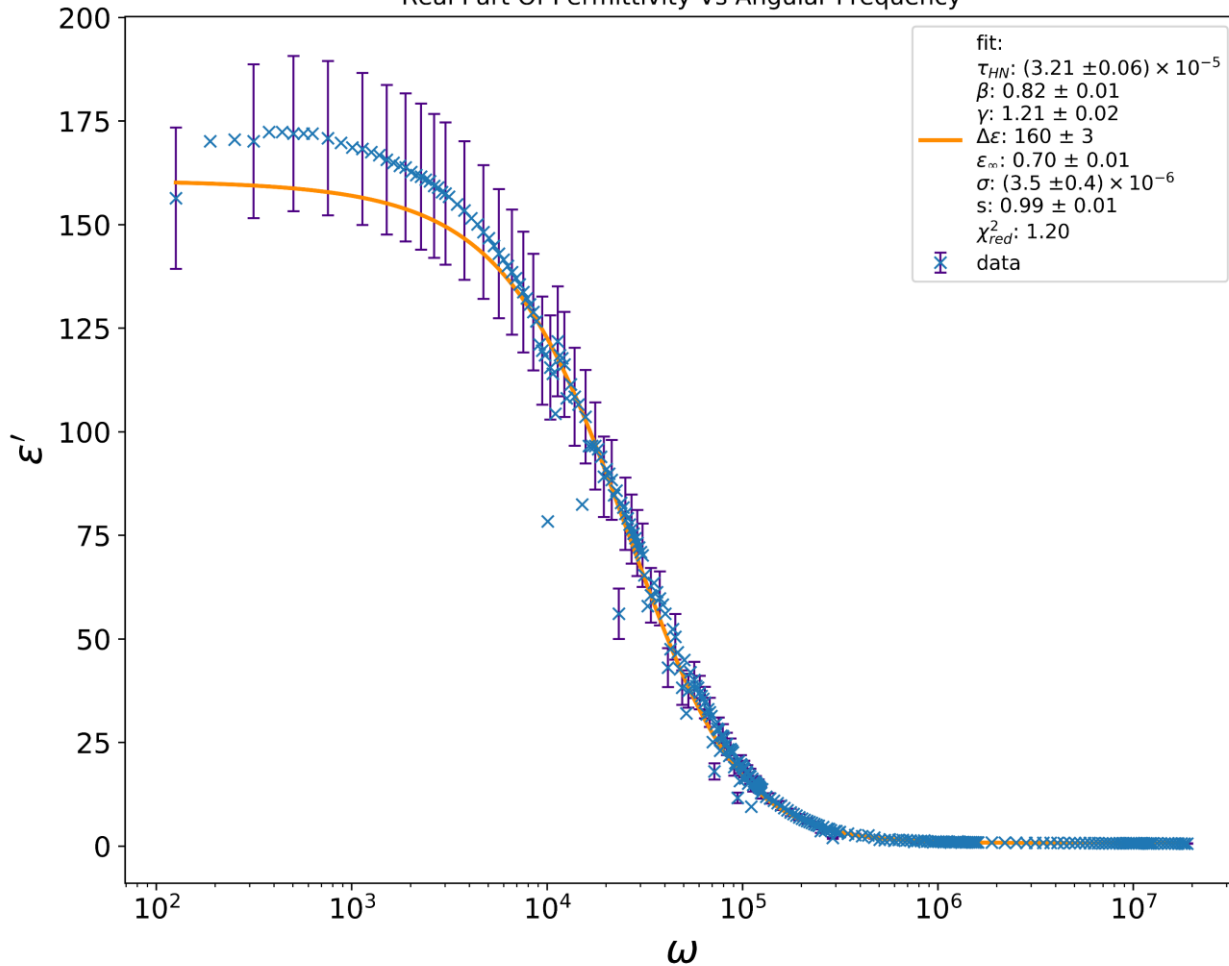
$$\begin{aligned}\Delta\varepsilon &= 160 \pm 3 \\ \beta &= 0,82 \pm 0,01 \\ \gamma &= 1,21 \pm 0,02 \\ \tau &= 3,21 \pm 0,06 (10^{-5})s \\ \varepsilon_{\infty} &= 0,70 \pm 0,01 \\ \sigma' &= 3,94 \pm 0,42 (10^5) [\Omega^{-1}m^{-1}\varepsilon_0] \\ s &= 0,99 \pm 0,02\end{aligned}$$

$$\chi_{red}^2 = 1,031$$

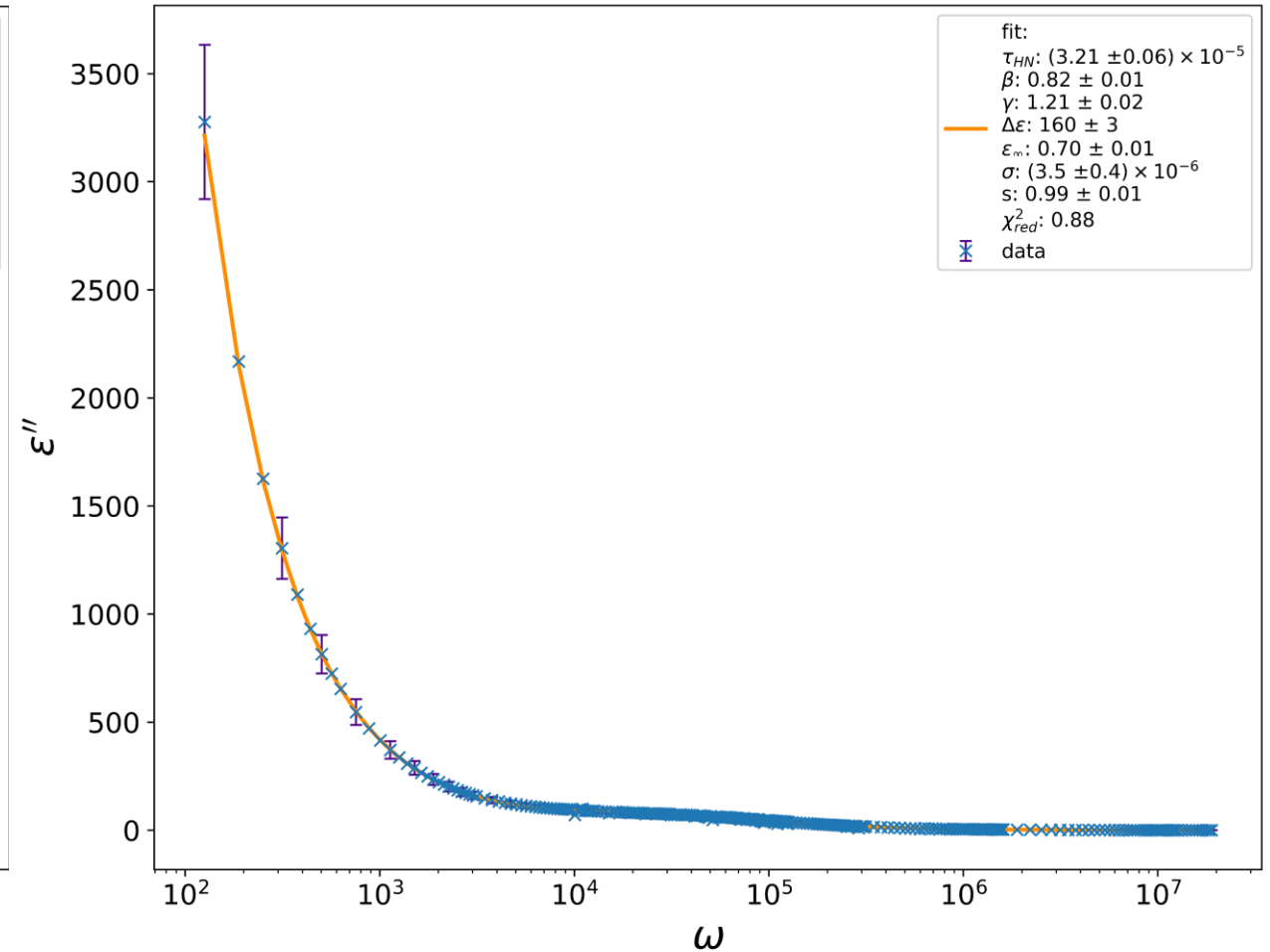
$$\sigma = 3,49 \pm 0,37 (10^{-6}) [\Omega^{-1}m^{-1}]$$

Scipy (curve_fit)

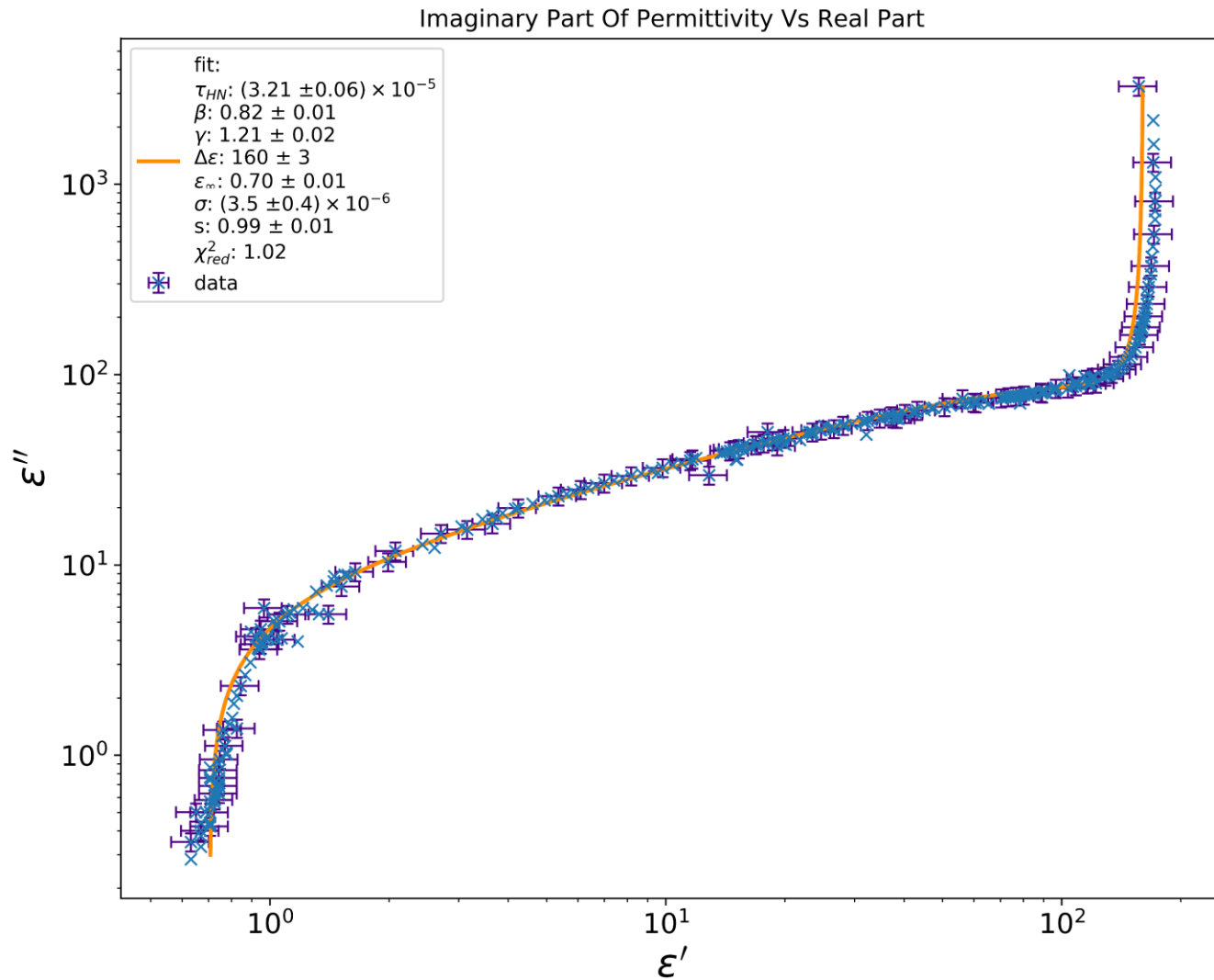
Real Part Of Permittivity Vs Angular Frequency



Imaginary Part Of Permittivity Vs Angular Frequency



Scipy



Goodness of fit: $\chi^2_{red} = 1.02$

Results:

$$\tau_{HN} : (3.21 \pm 0.06) \times 10^{-5}$$

$$\beta : 0.82 \pm 0.01$$

$$\gamma : 1.21 \pm 0.02$$

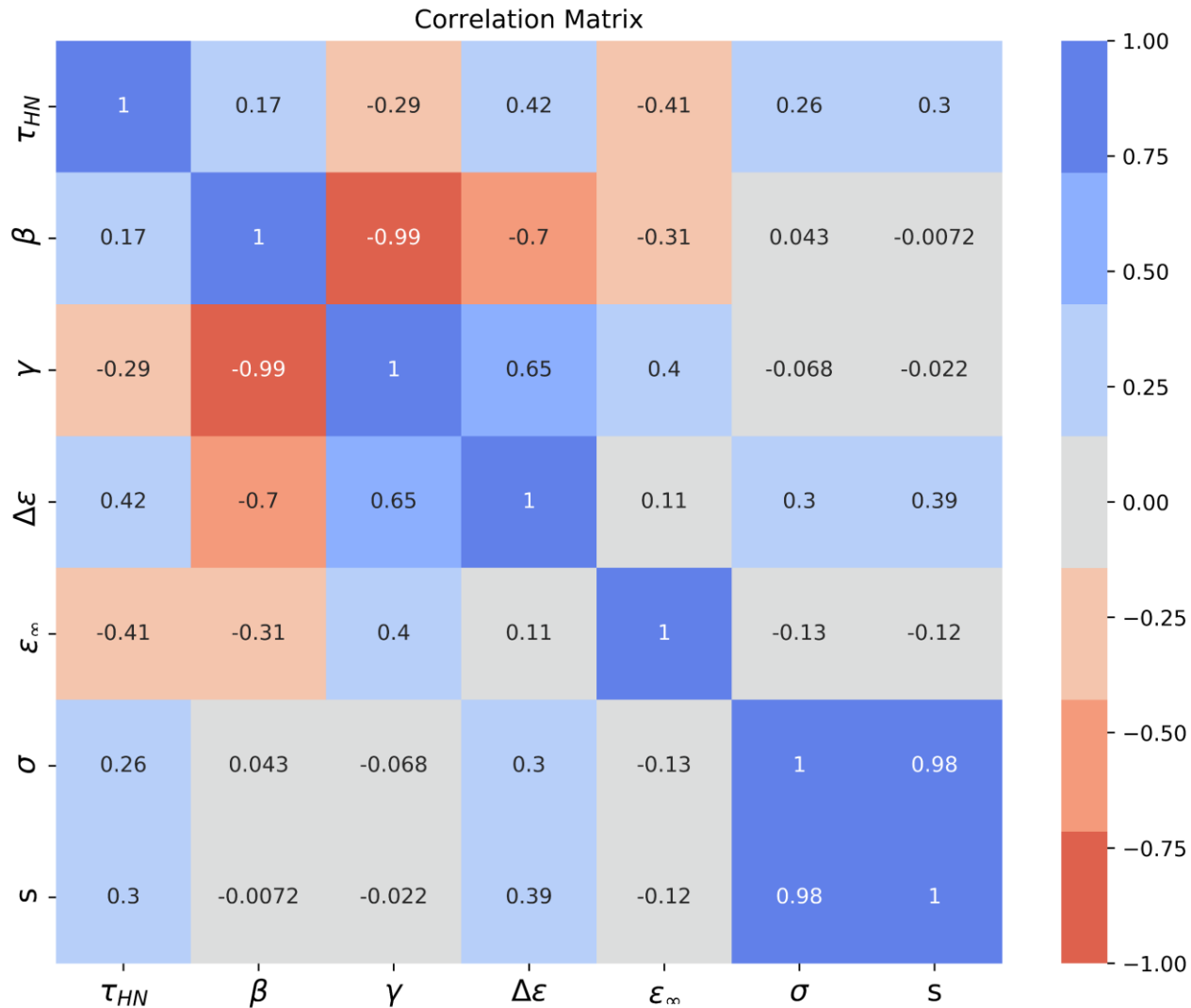
$$\Delta\epsilon : 160 \pm 3$$

$$\epsilon_{\infty} : 0.70 \pm 0.01$$

$$\sigma : (3.5 \pm 0.4) \times 10^{-6}$$

$$s : 0.99 \pm 0.01$$

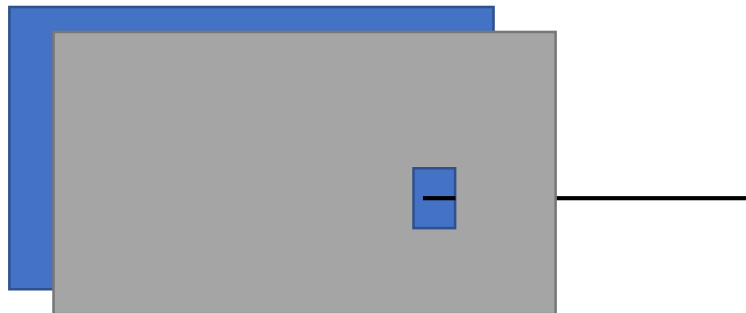
Correlation matrix



- β and γ are strongly anti-correlated. They obey the constraint relation: $0 < \beta\gamma \leq 1$
- DC conductivity is strongly correlated with s . Both parameters appear only in the additive term $\frac{\sigma_{DC}}{\epsilon_0\omega^s}$

Improving Measurements:

- Measuring thickness and area with a Scanning Electron Microscope (SEM).
- Changing the way the contact is made to improve the measurement of the area and smooth the surface:
 - Changing method: laser ablation deposition or sputtering
 - Use of a mask to limit the area and fix the contact to the material



Conclusion:

- We were able to obtain a fit that describes our data;
 - Havriliak-Negami equation with the conductivity term on the imaginary part can describe our data.
- In low frequencies, because our errors are so big, there is a little deviation between the data plot and the fit.
- To get better results the measurements should be improved, and the contact should be done with a new method, for example, laser or sputtering deposition.

OriginLab: Parameter errors and χ_{red}^2

Reduced χ^2 :

$$\chi_{red}^2 = \frac{\chi^2}{N - p} \qquad \chi^2 = \sum_{i=1}^N \frac{(Y_i - f(x_i))^2}{\sigma_i^2}$$

Calculating Parameter errors:

- Derivative matrix F: $F_{ij} = \frac{\partial f(x, \theta)}{\sigma_i \partial \theta_j}$
- *Variance-Covariance Matrix*: $C = (F'F)^{-1} \chi_{red}^2$
- Standard error: $s_{\theta_i} = \sqrt{C_{ii}}$